

NCE Automotive N-Channel Enhancement Mode Power MOSFET

General Features

• $V_{DS} = 60V, I_{D} = 0.3A$

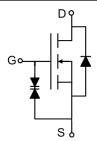
 $R_{DS(ON)}$ < 3 Ω @ V_{GS} =4.5V

 $R_{DS(ON)}$ < 2.2 Ω @ V_{GS} =10V

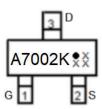
- High power and current handing capability
- Lead free product is acquired
- Surface mount package
- ESD Rating: HBM ≥1500V
- AEC-Q101 qualified

Application

- Automotive application
- Direct logic-level interface: TTL/CMOS
- Drivers: relays, solenoids, lamps, hammers, display, memories, transistors, etc.
- Battery operated systems
- Solid-state relays



Schematic diagram



Marking and pin assignment



SOT-23 top view

Package Marking And Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
A7002K [®] X	A2N7002K	SOT-23	Ø180mm	8 mm	3000 units

Absolute Maximum Ratings (T_A=25 ℃unless otherwise noted)

Parameter		Symbol	Limit	Unit	
Drain-Source Voltage		V _{DS}	60	V	
Gate-Source Voltage		Vgs	±20	V	
Oti	T _A =25℃	,	0.3	۸	
Continuous Drain Current (T _J =150℃)	T _A =100°C	I _D	0.19	Α	
Drain Current-Pulsed (Note 1)		I _{DM}	0.8	А	
Maximum Power Dissipation		P _D	0.35	W	
Operating Junction and Storage Temperature Range		T_{J}, T_{STG}	-55 To 150	°C	

Thermal Characteristic

Thermal Resistance, Junction-to-Ambient (Note 2)	R _{0JA}	350	°C/W



Electrical Characteristics (T_A=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Max	Unit
Off Characteristics			'	•	•	
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250μA	60	68	-	V
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =60V,V _{GS} =0V	-	-	1	μA
	I _{GSS}	V _{GS} =±10V,V _{DS} =0V	-	-	±1	uA
Gate-Body Leakage Current		V _{GS} =±20V,V _{DS} =0V	-		±10	uA
On Characteristics (Note 3)					l	1
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS},I_{D}=250\mu A$	0.7	1.3	1.9	V
		V _{GS} =4.5V, I _D =0.2A	-	1.95	3	Ω
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =10V, I _D =0.3A	-	1.8	2.2	Ω
Forward Transconductance	G FS	V _{DS} =10V,I _D =0.2A	0.1	-	-	S
Dynamic Characteristics (Note4)			•	•		
Input Capacitance	C _{lss}	\/ -05\/\/ -0\/	10	21	50	PF
Output Capacitance	Coss	V_{DS} =25 V , V_{GS} =0 V , F=1.0MHz	-	11	25	PF
Reverse Transfer Capacitance	C _{rss}	F-1.UIVITZ	-	4.2	5	PF
Switching Characteristics (Note 4)				•		
Turn-on Delay Time	t _{d(on)}		-	10	-	nS
Turn-on Rise Time	t _r	V_{DD} =30 V , I_D =0.2 A	-	50	-	nS
Turn-Off Delay Time	t _{d(off)}	$V_{GS}\text{=}10V, R_{GEN}\text{=}10\Omega$	-	17	-	nS
Turn-Off Fall Time	t _f		-	10	-	nS
Total Gate Charge	Q _g	V _{DS} =10V,I _D =0.3A,	_	1.7	3	nC
Total Gate Charge	₩	V _{GS} =4.5V				
Drain-Source Diode Characteristics						
Diode Forward Voltage (Note 3)	V _{SD}	V_{GS} =0 V , I_{S} =0.2 A	-	-	1.2	V
Diode Forward Current (Note 2)	Is		-	-	0.3	Α

Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, t ≤ 10 sec.
- 3. Pulse Test: Pulse Width ≤ 300µs, Duty Cycle ≤ 2%.
- 4. Guaranteed by design, not subject to production



Typical Electrical And Thermal Characteristics

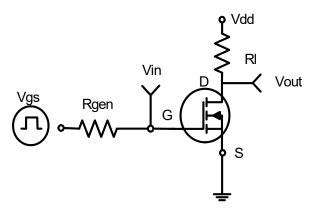


Figure 1:Switching Test Circuit

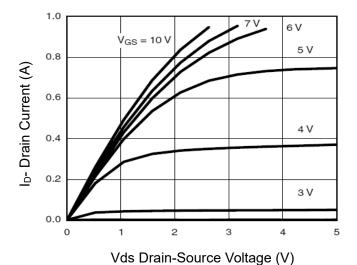


Figure 3 Output Characteristics

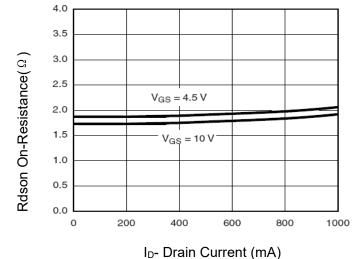


Figure 5 Drain-Source On-Resistance

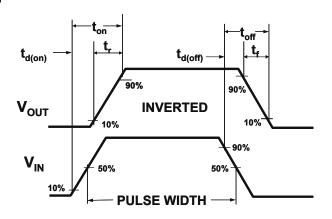


Figure 2:Switching Waveforms

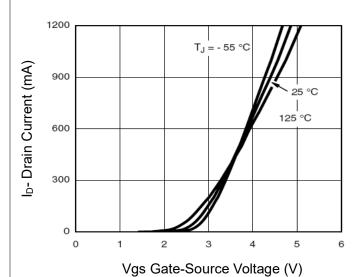
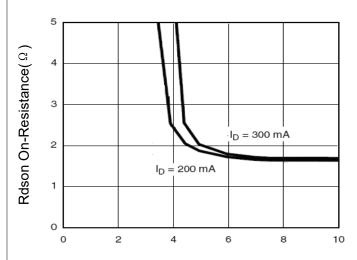
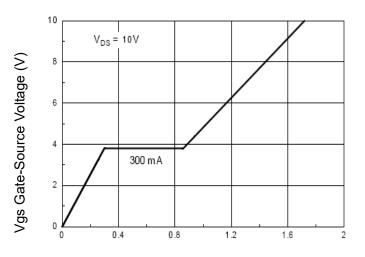


Figure 4 Transfer Characteristics



Vgs Gate-Source Voltage (V) Figure 6 Rdson vs Vgs





Qg Gate Charge (nC) Figure 7 Gate Charge

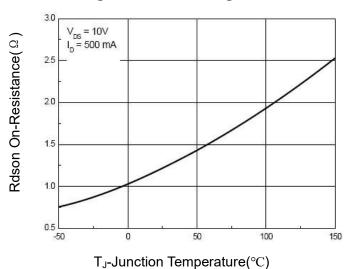


Figure 9 Drain-Source On-Resistance

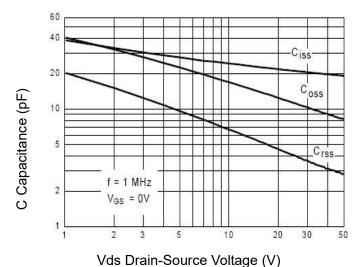
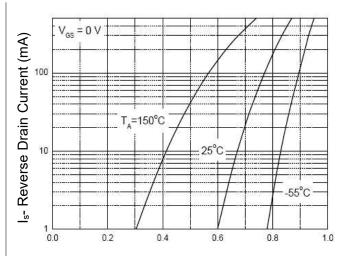
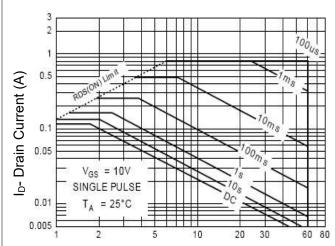


Figure 11 Capacitance vs Vds



Vsd Source-Drain Voltage (V)





Vds Drain-Source Voltage (V)

Figure 10 Safe Operation Area



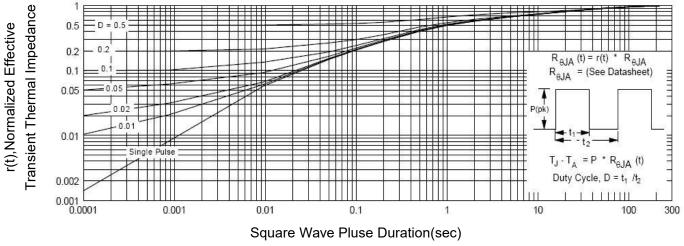
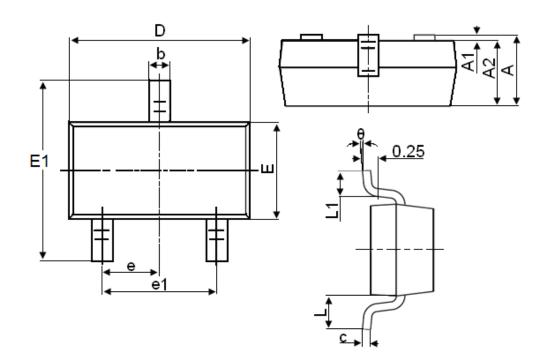


Figure 12 Normalized Maximum Transient Thermal Impedance



SOT-23 Package Information



Symbol	Dimensions in Millimeters			
	MIN.	MAX.		
А	0.900	1.150		
A1	0.000	0.100		
A2	0.900	1.050		
b	0.300	0.500		
С	0.080	0.150		
D	2.800	3.000		
Е	1.200	1.400		
E1	2.250	2.550		
е		0.950TYP		
e1	1.800	2.000		
L	0.550REF			
L1	0.300	0.500		
θ	0°	8°		

Notes

- 1. All dimensions are in millimeters.
- 2. Tolerance ±0.10mm (4 mil) unless otherwise specified
- 3. Package body sizes exclude mold flash and gate burrs. Mold flash at the non-lead sides should be less than 5 mils.
- 4. Dimension L is measured in gauge plane.
- 5. Controlling dimension is millimeter, converted inch dimensions are not necessarily exact

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